



DCP51/-16

PNP SURFACE MOUNT TRANSISTOR

Features

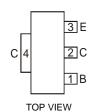
- **Epitaxial Planar Die Construction**
- Complementary NPN Type Available (DCP54)
- Ideally Suited for Automated Assembly Processes
- Ideal for Medium Power Switching or Amplification **Applications**
- Lead Free By Design/RoHS Compliant (Note 1)
 - "Green" Device (Note 2)

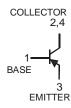
Mechanical Data

- Case: SOT-223
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Finish Matte Tin annealed over Copper leadframe (Lead Free Plating). Solderable per MIL-STD-202, Method 208
- Terminal Connections: See Diagram
- Marking & Type Code Information: See Page 3
- Ordering Information: See Page 3
- Weight: 0.115 grams (approximate)



SOT-223





Schematic and Pin Configuration

Maximum Ratings @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-45	V
Collector-Emitter Voltage	V _{CEO}	-45	V
Emitter-Base Voltage	V _{EBO}	-5	V
Peak Pulse Current	I _{CM}	-1.5	A
Continuous Collector Current	Ic	-1	A

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation @ T _A = 25°C (Note 3)	P _d	1 (Note 3)	W
Operating and Storage Temperature Range	$T_{j,}T_{STG}$	-55 to +150	°C
Thermal Resistance Junction to Ambient Air @ T _A = 25°C (Note 3)	$R_{\theta JA}$	125	°C/W

Electrical Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Тур	Max	Unit	Conditions
OFF CHARACTERISTICS (Note 4)						
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	-45	_		V	$I_C = -100 \mu A, I_E = 0 A$
Collector-Emitter Breakdown Voltage	V _{(BR)CEO}	-45	_		V	$I_C = -10 \text{mA}, I_B = 0 \text{A}$
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	-5	_	_	V	$I_E = -10\mu A, I_C = 0A$
Collector Cut-Off Current	Land	_	_	-100	nA	$V_{CB} = -30V, I_{E} = 0A$
	I _{CBO}	_	_	-10	μΑ	$V_{CB} = -30V$, $I_{E} = 0A$, $T_{A} = 150$ °C
Emitter Cut-Off Current	I _{EBO}	_	_	-10	μΑ	$V_{EB} = -5V, I_{C} = 0A$
ON CHARACTERISTICS (Note 4)						
Collector-Emitter Saturation Voltage	V _{CE(SAT)}		_	-0.5	V	$I_C = -500 \text{mA}, I_B = -50 \text{mA}$
Base-Emitter Turn-On Voltage	$V_{BE(ON)}$	_	_	-1.0	V	$I_C = -500 \text{mA}, V_{CE} = -2 \text{V}$
	b	40		250		$I_C = -150 \text{mA}, V_{CE} = -2 \text{V}$
DC Current Gain	h _{FE}	25	_	_		$I_C = -500 \text{mA}, V_{CE} = -2 \text{V}$
DCP51-16		100	_	250		$I_C = -150 \text{mA}, V_{CE} = -2 \text{V}$
SMALL SIGNAL CHARACTERISTICS						
Transition Frequency	f _T	_	200	_	MHz	$I_C = -50 \text{mA}, V_{CE} = -5 \text{V},$ f = 100 MHz

Note:

- 1. No purposefully added lead.
- 2. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.
 3. Device mounted on FR-4 PCB pad layout as shown on page 4 or on Diodes, Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.
- 4. Measured under pulsed conditions. Pulse width = 300μs. Duty cycle ≤2%

© Diodes Incorporated



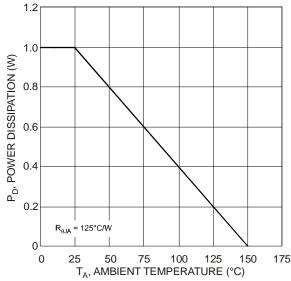


Fig. 1 Power Dissipation vs. Ambient Temperature (Note 3)

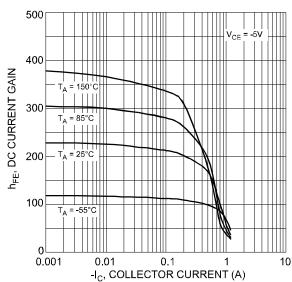


Fig. 3 Typical DC Current Gain vs. Collector Current

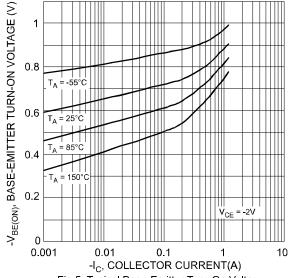


Fig 5. Typical Base-Emitter Turn-On Voltage vs. Collector Current

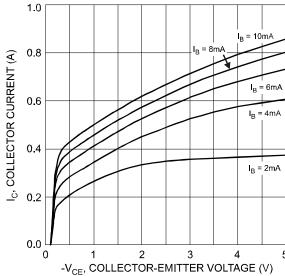


Fig. 2 Typical Collector Current vs. Collector-Emitter Voltage

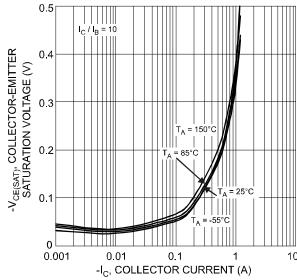


Fig. 4 Typical Collector-Emitter Saturation Voltage vs. Collector Current

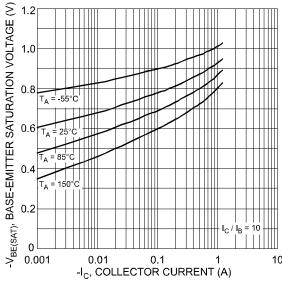
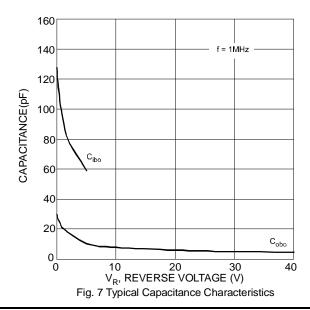


Fig. 6 Typical Base-Emitter Saturation Voltage vs. Collector Current

2 of 4

www.diodes.com





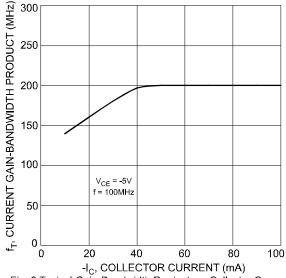


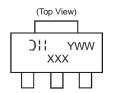
Fig. 8 Typical Gain-Bandwidth Product vs. Collector Current

Ordering Information (Note 5)

Part Number	Case	Packaging
DCP51-13	SOT-223	2500 / Tape & Reel
DCP51-16-13	SOT-223	2500 / Tape & Reel

Notes: 5. For packaging details, please visit our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information

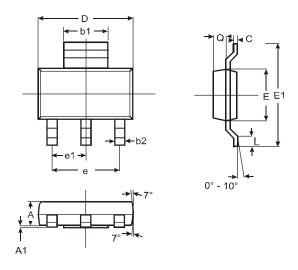


III = Manufacturer's code marking

XXX = Product type marking code Ex:

YWW = Date code marking Y = Last digit of year ex: 7 = 2007 WW = Week code 01 - 52

Package Outline Dimensions



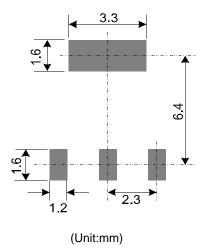
SOT-223					
Dim	Min	Max	Тур		
Α	1.55	1.65	1.60		
A1	0.010	0.15	0.05		
b1	2.90	3.10	3.00		
b2	0.60	0.80	0.70		
С	0.20	0.30	0.25		
D	6.45	6.55	6.50		
Е	3.45	3.55	3.50		
E1	6.90	7.10	7.00		
е	_	_	4.60		
e1	_	_	2.30		
L	0.85	1.05	0.95		
Q	0.84	0.94	0.89		
All Dimensions in mm					

P14 = DCP51

P14-16 = DCP51-16



Suggested Pad Layout: (Based on IPC-SM-782)



IMPORTANT NOTICE

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to any product herein. Diodes Incorporated does not assume any liability arising out of the application or use of any product described herein; neither does it convey any license under its patent rights, nor the rights of others. The user of products in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on our website, harmless against all damages.

LIFE SUPPORT

Diodes Incorporated products are not authorized for use as critical components in life support devices or systems without the expressed written approval of the President of Diodes Incorporated.

DCP51/-16

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Bipolar Transistors - BJT category:

Click to view products by Diodes Incorporated manufacturer:

Other Similar products are found below:

619691C MCH4017-TL-H BC546/116 BC557/116 BSW67A NTE187A NTE195A NTE2302 NTE2330 NTE63 C4460 2SA1419T-TD-H 2SA1721-O(TE85L,F) 2SA2126-E 2SB1204S-TL-E 2SC5488A-TL-H 2SD2150T100R SP000011176 2N2369ADCSM 2SC2412KT146S 2SC5490A-TL-H 2SD1816S-TL-E 2SD1816T-TL-E CMXT2207 TR CPH6501-TL-E MCH4021-TL-E US6T6TR 732314D CMXT3906 TR CPH3121-TL-E CPH6021-TL-H 873787E UMX21NTR EMT2T2R MCH6102-TL-E FP204-TL-E NJL0302DG 2N3583 2N3879 2SA1434-TB-E 2SC3143-4-TB-E 2SD1621S-TD-E 30A02MH-TL-E NSV40301MZ4T1G NTE13 NTE15 NTE16001 NTE16006 NTE26 NTE320